INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC24 1999 Sep 01



74LVC322245A; 74LVCH322245A

FEATURES

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range of 1.2 to 3.6 V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTE™ flow-trough standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Bus hold on data inputs (74LVCH322245A only)
- Integrated 30 Ω termination resistors
- Typical output ground bounce voltage: V_{OLP} <0.8 V at V_{CC} = 3.3 V; T_{amb} = 25 °C
- Typical output V_{OH} undershoot voltage: V_{OHV} >2 V at V_{CC} = 3.3 V; T_{amb} = 25 °C
- Power-off disabled outputs, permitting live insertion
- Plastic fine-pitch ball grid array package.

DESCRIPTION

The 74LVC(H)322245A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families. Inputs can be driven from either 3.3 or 5 V devices. In 3-state operation, outputs can handle 5 V. These features allow the use of these devices in a mixed 3.3 and 5 V environment.

The 74LVC(H)322245A is a 32-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74LVC(H)322245A features two output enable (n $\overline{\text{OE}}$) inputs for easy cascading and two send or receive (nDIR) inputs for direction control. n $\overline{\text{OE}}$ controls the outputs so that the buses are effectively isolated. The 74LVC(H)322245A is designed with 30 Ω series termination resistors in both HIGH and LOW output stages to reduce line noise.

To ensure the high-impedance state during power-up or power-down, input $n\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The 74LVCH322245A bus hold data inputs eliminates the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level (see Fig.2).

QUICK REFERENCE DATA

Ground = 0 V; $T_{amb} = 25 \text{ °C}$; $t_r = t_f \le 2.5 \text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	propagation delay nA _n to nB _n ; nB _n to nA _n	$C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	3.3	ns
CI	input capacitance		5.0	pF
C _{I/O}	input/output capacitance		10	pF
C _{PD}	power dissipation capacitance per buffer	$V_{I} = GND$ to V_{CC} ; note 1	28	pF

Note

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

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FUNCTION TABLE

See note 1.

INF	TUT	OUTPUT		
nOE	nDIR	nA _n	nB _n	
L	L	A = B	inputs	
L	Н	inputs	B = A	
Н	Х	Z	Z	

Note

- 1. H = HIGH voltage level;
 - L = LOW voltage level;
 - X = don't care;
 - Z = high-impedance OFF-state.

ORDERING INFORMATION

ORDERING INFORMATION			-R			
TYPE NUMBER	PACKAGES					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	
74LVC322245AEC	–40 to +85 °C	96	LFBGA96	plastic	SOT536-1	
74LVCH322245AEC		96	LFBGA96	plastic	SOT536-1	
PINNING						

PINNING

SYMBOL	DESCRIPTION
nDIR	direction control
nOE	output enable input (active LOW)
nA _n	data inputs/outputs
nB _n	data inputs/outputs
GND	ground (0 V)
V _{CC}	DC supply voltage

6

5

4

3

2

1

1A₁

1A₀ 1A₂

10E

1DIR

1B₀

1B₁

1A3 1A5 1A7

GND

GND

1B₂

1B3 1B₅

1A₄ 1A₆

Vcc

Vcc

1B₄

GND

GND

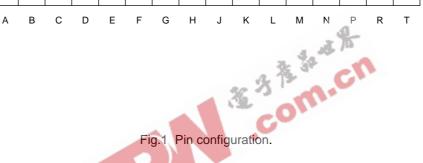
1B₆

1B7

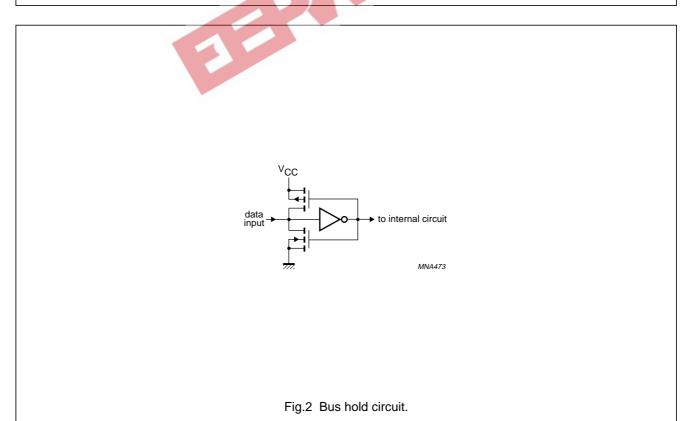
74LVC322245A;

32-bit bus transceiver with direction pin; 30 Ω series termination resistors; 5 V tolerant; 3-state

74LVCH322245A MNA475 2A5 4A₆ 2A1 2A3 2A₆ 3A1 3A3 3A5 3A7 4A1 4A3 4A5 2A₇ 3A₀ 3A₄ 4A4 2A₀ 2A₂ 2A4 3A₂ 3A₆ 4A₀ 4A2 4A7 GND V_{CC} V_{CC} GND GND GND 20E 30E GND GND 40E Vcc GND GND 2DIR 3DIR GND GND GND GND 4DIR Vcc VCC Vcc 2B4 2B7 3B₀ 4B₀ 4B₄ 4B7 2B2 3B4 4B₂ 2B₀ 3B₂ 3B₆ 2B3 4B3 2B₆ 3B₅ 2B₁ 2B5₁ 3B₁ 3B3 3B7 4B₁ $4B_5$ 4B₆

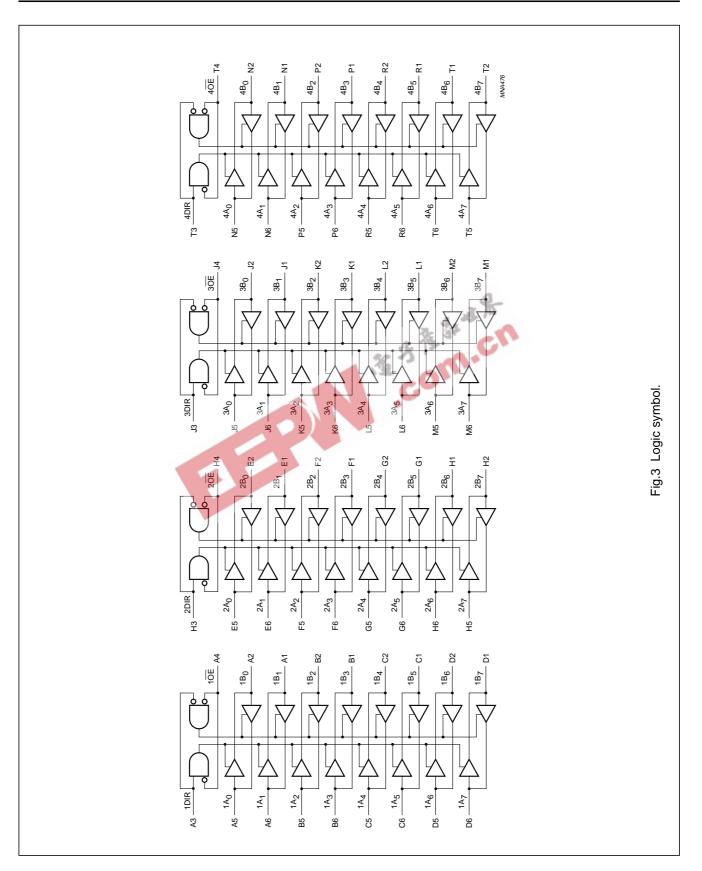






Product specification

32-bit bus transceiver with direction pin; 30 Ω74LVC322245A;series termination resistors; 5 V tolerant; 3-state74LVCH322245A



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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LI	LIMITS	
STWIDUL		CONDITIONS	MIN.	MAX.	
V _{CC}	DC supply voltage	for max. speed performance	2.7	3.6	V
		or low-voltage applications	1.2	3.6	V
VI	DC input voltage		0	5.5	V
Vo	DC output voltage	output HIGH or LOW state	0	V _{CC}	V
		3-state	0	5.5	V
T _{amb}	operating ambient temperature	see DC and AC characteristics per device	-40	+85	°C
$t_r, t_f (\Delta t / \Delta f)$	input rise and fall times	V _{CC} = 1.2 to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ to 3.6 V	0	10	

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	DC supply voltage	28 ·3	-0.5	+6.5	V
VI	DC input voltage	note 1	-0.5	+6.5	V
I _{IK}	DC input diode current	V _I < 0	-	-50	mA
I _{OK}	DC output diode current	$V_0 > V_{CC}$ or $V_0 < 0$; note 1	_	±50	mA
Vo	DC output voltage	output HIGH or LOW state; note 1	-0.5	V _{CC} + 0.5	V
		output 3-state; note 1	-0.5	+6.5	V
lo	DC output source or sink current	$V_{O} = 0$ to V_{CC}	_	±50	mA
I _{CC} , I _{GND}	DC V _{CC} or GND current		-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _D	power dissipation per package	temperature range: -40 to +85 °C; note 2	_	1000	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. Above 70 $^{\circ}\text{C}$ the value of P_D derates linearly with 1.8 mW/K.

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DC CHARACTERISTICS

Over recommended operating conditions; voltage are referenced to GND (ground = 0 V).

		TEST CONDITIONS		T _{amb} (°C)			
SYMBOL	PARAMETER		V _{cc} (V)	-40 to +85			UNIT
		OTHER		MIN.	TYP. ⁽¹⁾	MAX.	1
VIH	HIGH-level input voltage		1.2	V _{CC}	-	-	V
			2.7 to 3.6	2.0	-	-	1
V _{IL}	LOW-level input voltage		1.2	-	-	GND	V
			2.7 to 3.6	-	-	0.8	
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I _O = -6 mA	2.7	$V_{CC} - 0.5$	-	-	V
		I _O = −100 μA	3.0	$V_{CC} - 0.2$	V _{CC}	-	
		I _O = -12 mA	3.0	$V_{CC} - 0.8$	-	-	
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$	4	2			
		I _O = 6 mA	2.7	B <u>)</u>	-	0.40	V
		I _O = 100 μA	3.0		-	0.20	
		l _o = 12 mA 🛛 👷 🎝	3.0	_	-	0.55	
l _l	input leakage current	$V_{I} = 5.5 V \text{ or GND};$ note 2	3.6	-	±0.1	±5	μA
I _{OZ}	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	3.6	-	0.1	±5	μA
I _{off}	power off leakage supply current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0.0	-	0.1	±10	μA
I _{CC}	quiescent supply current	$V_{\rm I} = V_{\rm CC}$ or GND; $I_{\rm O} = 0$	3.6	-	0.1	40	μA
ΔI_{CC}	additional quiescent supply current per data input pin	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0$	2.7 to 3.6	-	5	500	μA
I _{BHL}	bus hold LOW sustaining current	V _I = 0.8 V; notes 3, 4 and 5	3.0	75	-	-	μA
I _{BHH}	bus hold HIGH sustaining current	V _I = 2.0 V; notes 3, 4 and 5	3.0	-75	-	-	μA
I _{BHLO}	bus hold LOW overdrive current	notes 3, 4 and 6	3.6	450	-	-	μA
I _{BHHO}	bus hold HIGH overdrive current	notes 3, 4 and 6	3.6	-450	-	-	μA

Notes

1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

2. For bus hold parts the bus hold circuit is switched off when V_1 exceeds V_{CC} allowing 5.5 V on the input terminal.

- 3. Valid for data inputs of bus hold parts only (LVCH32xxx-A).
- 4. For data inputs only. Control inputs do not have a bus hold circuit.
- 5. The specified sustaining current at the data input holds the input below the specified V_I level.
- 6. The specified overdrive current at the data input forces the data input to the opposite logic input level.

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AC CHARACTERISTICS

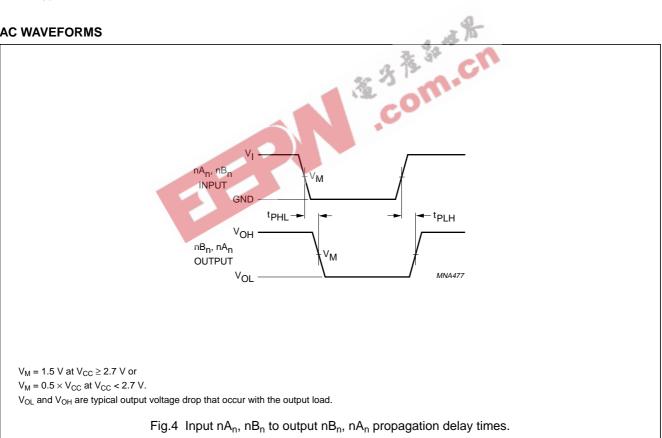
GND = 0 V; $t_r = t_f \le 2.5 \text{ ns}$; $C_L = 50 \text{ pF}$; $R_L = 500 \Omega$.

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} = −40 to +85 °C			
STWBOL	PARAMETER	WAVEFORMS	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	
t _{PHL} /t _{PLH}	propagation delay	see Figs 4 and 6	2.7	1.5	-	6.7	ns
	nA _n to nB _n ; nB _n to nA _n		3.0 to 3.6	1.5	3.3	5.7	
t _{PZH} /t _{PZL}	3-state output enable time	see Figs 5 and 6	2.7	1.5	-	8.5	ns
	$n\overline{OE}$ to nA_n ; $n\overline{OE}$ to nB_n		3.0 to 3.6	1.5	4.3	7.5	
t _{PHZ} /t _{PLZ}	3-state output disable time	see Figs 5 and 6	2.7	1.5	-	7.5	ns
	$n\overline{OE}$ to nA_n ; $n\overline{OE}$ to nB_n		3.0 to 3.6	1.5	4.0	6.5	

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

AC WAVEFORMS

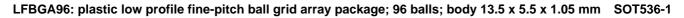


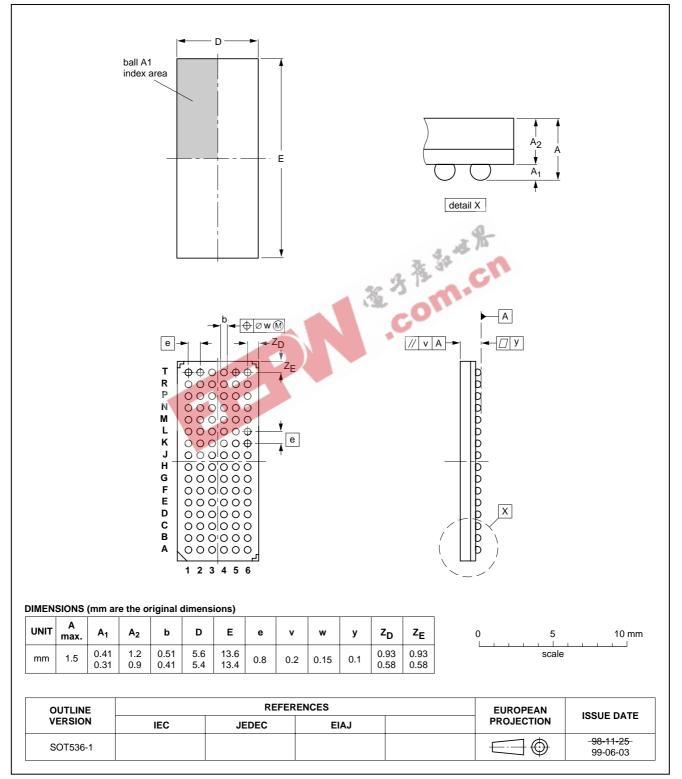
32-bit bus transceiver with direction pin; 30 Ω 74LVC322245A; series termination resistors; 5 V tolerant; 3-state 74LVCH322245A Vı nOE INPUT ٧м GND - ^tPLZ ^tPZL Vcc OUTPUT LOW-to-OFF ٧м OFF-to-LOW ٧x VOL ^tPHZ ⊢^tPZH **→** VOH OUTPUT HIGH-to-OFF OFF-to-HIGH ٧M GND outputs outputs outputs enabled enabled disabled MNA478 V_M = 1.5 V at $V_{CC} \geq 2.7$ V or V_{M} = 0.5 \times V_{CC} at V_{CC} < 2.7 V; V_X = V_{OL} + 0.3 V at $V_{CC} \geq 2.7$ V or $V_X = V_{OL} + 0.1 \text{ V} \text{ at } V_{CC} < 2.7 \text{ V};$ V_{Y} = $V_{OH} - 0.3$ V at $V_{CC} \geq 2.7$ V or V_{Y} = V_{OH} - 0.1 V at V_{CC} < 2.7 V; VoL and VoH are typical output voltage drop that occur with the output load. Fig.5 3-state enable and disable times. S $2 \times V_{CC}$ open Vcc – GND R_L 500 Ω ۷o PULSE D.U.1 GENERATOR R_L С_L 50 рF RT 500 Ω MNA479 TEST S₁ Definitions for test circuit: Vcc ٧ı t_{PLH}/t_{PHL} open R_L = load resistor. C_L = load capacitance including jig and probe capacitance. < 2.7 V t_{PLZ}/t_{PZL} $2 \times V_{\text{CC}}$ V_{CC} R_T = termination resistance should be equal to the output impedance 2.7 to 3.6 V 2.7 V GND t_{PHZ}/t_{PZH} Zo of the pulse generator.

Fig.6 Load circuitry for switching times.

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PACKAGE OUTLINE





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SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 230 °C.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ\text{C}.$

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD		
FACKAGE	WAVE	REFLOW ⁽¹⁾	
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable	
HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable ⁽²⁾	suitable	
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable	
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.

Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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NOTES



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